N-Channel Silicon MOSFET



FSS244

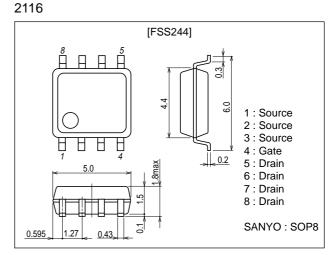
DC / DC Converter Applications

Features

- · Low ON-resistance.
- 4V drive.
- Ultrahigh speed switching.

Package Dimensions

unit : mm



Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	VDSS		30	V
Gate-to-Source Voltage	VGSS		±20	V
Drain Current (DC)	۱ _D		10	А
Drain Current (Pulse)	IDP	PW≤10µs, duty cycle≤1%	52	А
Allowable Power Dissipation	PD	Mounted on a ceramic board (1200mm ² X0.8mm) 1unit	2.0	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Onit
Drain-to-Source Breakdown Voltage	V(BR)DSS	ID=1mA, VGS=0	30			V
Zero-Gate Voltage Drain Current	IDSS	VDS=30V, VGS=0			1	μΑ
Gate-to-Source Leakage Current	IGSS	V _{GS} =±16V, V _{DS} =0			±10	μΑ
Cutoff Voltage	V _{GS} (off)	V _{DS} =10V, I _D =1mA	1.0		2.4	V
Forward Transfer Admittance	yfs	V _{DS} =10V, I _D =10A	12	18		s

Marking : S244

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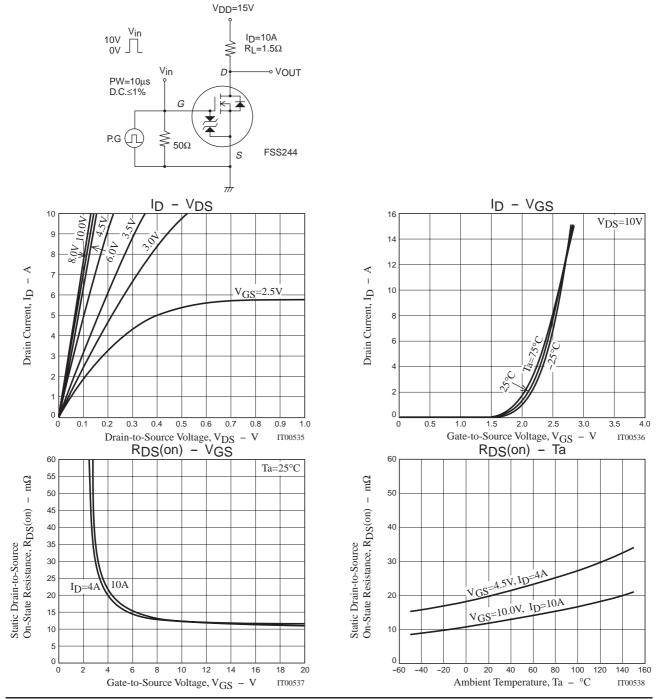
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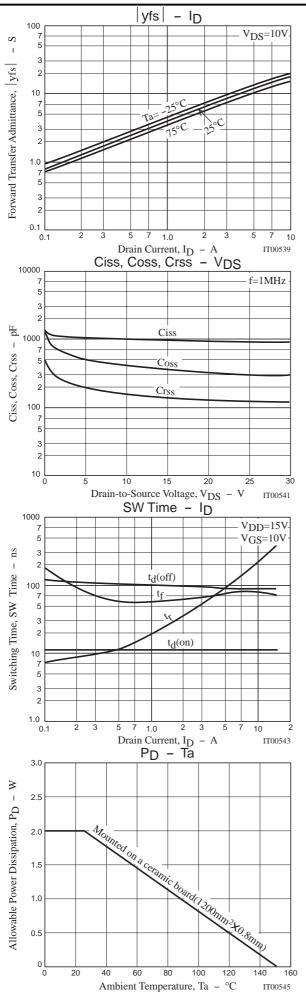
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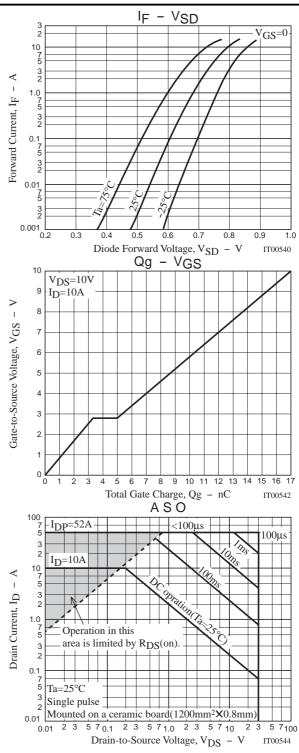
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Parameter	Symbol	Conditions	Ratings			
			min	typ	max	Unit
Static Drain-to-Source On-State Resistance	R _{DS} (on)1	ID=10A, VGS=10V		13	17	mΩ
	R _{DS} (on)2	ID=4A, VGS=4.5V		20	28	mΩ
Input Capacitance	Ciss	VDS=10V, f=1MHz		980		pF
Output Capacitance	Coss	V _{DS} =10V, f=1MHz		410		pF
Reverse Transfer Capacitance	Crss	V _{DS} =10V, f=1MHz		170		pF
Turn-ON Delay Time	t _d (on)	See specified Test Circuit		11		ns
Rise Time	tr	See specified Test Circuit		210		ns
Turn-OFF Delay Time	t _d (off)	See specified Test Circuit		80		ns
Fall Time	tf	See specified Test Circuit		85		ns
Total Gate Charge	Qg	V _{DS} =10V, V _{GS} =10V, I _D =10A		17		nC
Gate-to-Source Charge	Qgs	V _{DS} =10V, V _{GS} =10V, I _D =10A		3.3		nC
Gate-to-Drain "Miller" Charge	Qgd	V _{DS} =10V, V _{GS} =10V, I _D =10A		1.7		nC
Diode Forward Voltage	VSD	IS=10A, VGS=0		0.8	1.2	V

Switching Time Test Circuit







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